

TC514260BJ/BFT-70/80

262,144 WORD X 16 BIT DYNAMIC RAM

DESCRIPTION

The TC514260BJ/BFT is the new generation dynamic RAM organized 262,144 word by 16 bit. The TC514260BJ/BFT utilizes Toshiba's CMOS silicon gate process technology as well as advanced circuit techniques to provide wide operating margins, both internally and to the system user. Multiplexed address inputs permit the TC514273BJ to be packaged in a standard 40 pin plastic SOJ, and 44/40 pin plastic TSOP. The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of $5V \pm 10\%$ tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

FEATURES

- 262,144 word by 16 bit organization
- Fast access time and cycle time
- Single power supply of $5V \pm 10\%$ with a built-in V_{BB} generator
- Low Power
 - 550mW MAX. Operating (TC514273BJ-70)
 - 468mW MAX. Operating (TC514273BJ-80)
 - 5.5mW MAX. Standby
- Outputs unlatched at cycle end allows two-dimensional chip selection
- Read-Modify-Write, CAS before RAS refresh, RAS-only refresh, Hidden refresh, Fast Page Mode and Test Mode capability
- All inputs and outputs TTL compatible
- 512refresh cycles/8ms
- Package TC514260BJ : SOJ40-P-400
TC514260BFT : TSOP44-P-400B

KEY PARAMETERS

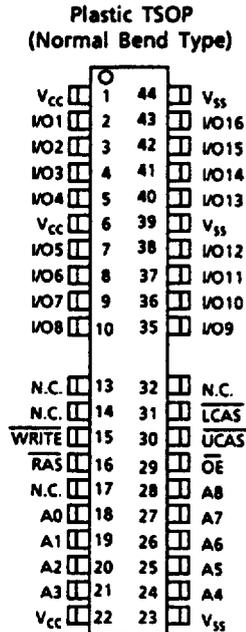
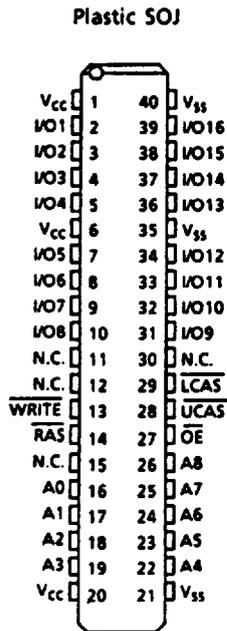
ITEM	TC514260BJ	
	-70	-80
t_{RAC} RAS Access Time	70ns	80ns
t_{AA} Column Address Access Time	35ns	40ns
t_{CAC} CAS Access Time	20ns	20ns
t_{RC} Cycle Time	130ns	150ns
t_{PC} Fast Page Mode Cycle Time	45ns	50ns

TC514260BJ/BFT-70/80

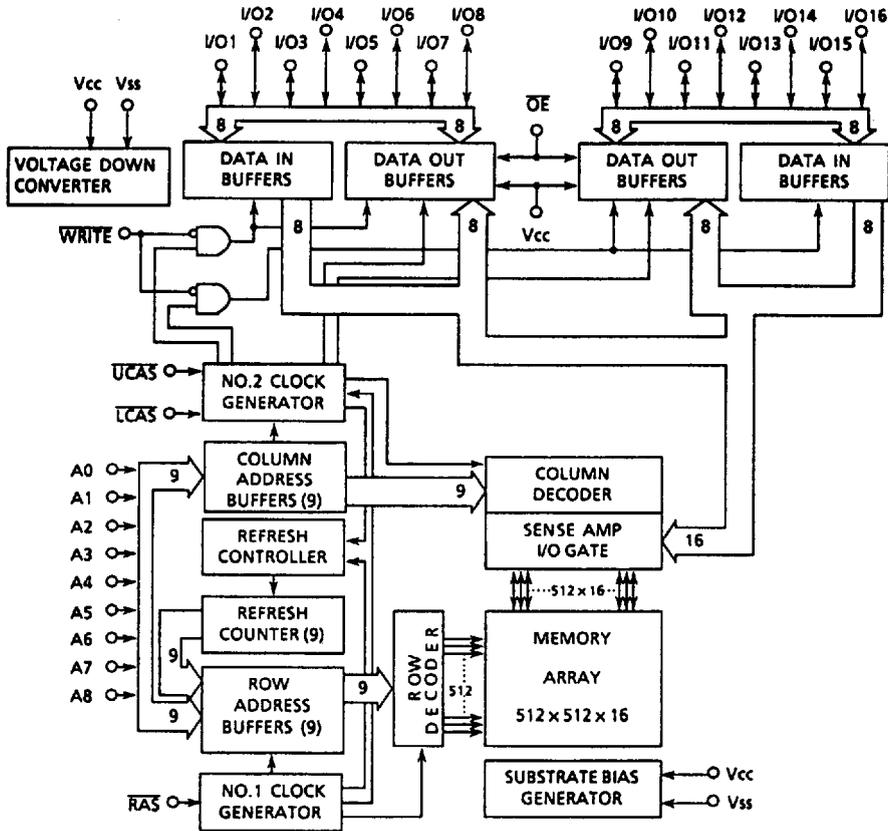
PIN NAME

A0~A8	Address Inputs
RAS	Row Address Strobe
UCAS	Column Address Strobe/Upper Byte Control
LCAS	Column Address Strobe/Lower Byte Control
WRITE	Read/Write Input
OE	Output Enable
I/O1~I/O16	Write Section/ Data Input/Output
V _{CC}	Power (+5V)
V _{SS}	Ground
N.C.	No Connection

PIN CONNECTION (TOP VIEW)



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

ITEM	SYMBOL	RATING	UNIT	NOTE
Input Voltage	V_{IN}	-1~7	V	1
Output Voltage	V_{OUT}	-1~7	V	1
Power Supply Voltage	V_{CC}	-1~7	V	1
Operating Temperature	T_{OPR}	0~70	°C	1
Storage Temperature	T_{STG}	-55~150	°C	1
Soldering Temperature • Time	T_{SOLDER}	260 • 10	°C • sec	1
Power Dissipation	P_D	700	mW	1
Short Circuit Output Current	I_{OUT}	50	mA	1

TC514260BJ/BFT-70/80

RECOMMENDED D.C. OPERATING CONDITION (Ta = 0~70°C)

SYMBOL	PARAMETER	MIN.	TYP	MAX	UNIT	NOTE
V _{CC}	Supply Voltage	4.5	5.0	5.5	V	2
V _{IH}	Input High Voltage	2.4	-	V _{CC} +0.5	V	2
V _{IL}	Input Low Voltage	-0.5	-	0.8	V	2

*-2.0V at pulse width ≤ 20ns

D.C. OPERATING CHARACTERISTICS (V_{CC} = 5V ± 10%, Ta = 0~70°C)

SYMBOL	PARAMETER		MIN.	MAX	UNIT	NOTE
I _{CC1}	OPERATING CURRENT Average Power Supply Operating Current (RAS, UCAS, LCAS, Address Cycling: t _{RC} =t _{RC} MIN.)	TC514260BJ/BFT-70	-	100	mA	3, 4 5
		TC514260BJ/BFT-80	-	85		
I _{CC2}	STANDBY CURRENT Power Supply Standby Current (RAS=UCAS=LCAS=V _{IH})			2	mA	
I _{CC3}	RAS ONLY REFRESH CURRENT Average Power Supply Current, RAS Only Mode(RAS Cycling, UCAS=LCAS=V _{IH} : t _{RC} =t _{RC} MIN.)	TC514260BJ/BFT-70	-	100	mA	3, 5
		TC514260BJ/BFT-80	-	85		
I _{CC4}	FAST PAGE MODE CURRENT Average Power Supply Current, Fast Page Mode(RAS=V _{IL} , UCAS, LCAS, Address Cycling: t _{PC} =t _{PC} MIN.)	TC514260BJ/BFT-70	-	70	mA	3, 4 5
		TC514260BJ/BFT-80	-	60		
I _{CC5}	STANDBY CURRENT Power Supply Standby Current (RAS=UCAS=LCAS=V _{CC} -0.2V)			1	mA	
I _{CC6}	CAS BEFORE RAS REFRESH CURRENT Average Power Supply Current, CAS Before RAS Mode (RAS, UCAS, LCAS Cycling: t _{RC} =t _{PC} MIN.)	TC514260BJ/BFT-70	-	100	mA	3, 5
		TC514260BJ/BFT-80	-	85		
I _{I(L)}	INPUT LEAKAGE CURRENT Input Leakage Current, any input (0V ≤ V _{IN} ≤ 6.5V, All Other Pins Not Under Test=0V)		-10	10	μA	
I _{O(L)}	OUTPUT LEAKAGE CURRENT (D _{OUT} is disabled, 0V ≤ V _{OUT} ≤ 5.5V)		-10	10	μA	
V _{OH}	OUTPUT CURRENT Output "H" Level Voltage (I _{OUT} =-5mA)		2.4	-	V	
V _{OL}	OUTPUT CURRENT Output "L" Level Voltage (I _{OUT} =4.2mA)		-	0.4	V	

ELECTRICAL CHARACTERISTICS AND RECOMMENDED A.C. OPERATING CONDITIONS ($V_{CC} = 5V \pm 10\%$, $T_a = 0\sim 70^\circ C$)(Notes 6,7,8)

SYMBOL	PARAMETER	TC514260BJ/BFT				UNIT	NOTES
		-70		-80			
		MIN	MAX.	MIN	MAX		
t_{RC}	Random Read or Write Cycle Time	130	-	150	-	ns	
t_{RMW}	Read-Modify-Write Cycle	185	-	205	-	ns	
t_{PC}	Fast Page Mode Cycle Time	45	-	50	-	ns	
t_{PRMW}	Fast Page Mode Read-Modify-Write Cycle Time	100	-	105	-	ns	
t_{RAC}	Access Time from \overline{RAS}	-	70	-	80	ns	9,14,15
t_{CAC}	Access Time from \overline{CAS}	-	20	-	20	ns	9,14
t_{AA}	Access Time from Column Address	-	35	-	40	ns	9,15
t_{CPA}	Access Time from \overline{CAS} Precharge	-	40	-	45	-	9
t_{CLZ}	\overline{CAS} to Output in Low-Z	0	-	0	-	ns	9
t_{OFF}	Output Buffer Turn-off Delay	0	15	0	15	ns	10
t_T	Transition Time (Rise and Fall)	3	50	3	50	ns	
t_{RP}	\overline{RAS} Presharge Time	50	-	60	-	ns	
t_{RAS}	\overline{RAS} Pulse Width	70	10,000	80	10,000	ns	
t_{RASP}	\overline{RAS} Pulse Width (Fast Page Mode)	70	100,000	80	100,000	ns	
t_{RSH}	\overline{RAS} Hold Time	20	-	20	-	ns	
t_{RHCP}	\overline{RAS} Hold Time From \overline{CAS} Precharge (Fast Page Mode)	40	-	45	-	ns	
t_{CSH}	\overline{CAS} Hold Time	70	-	80	-	ns	
t_{CAS}	\overline{CAS} Pulse Width	20	10,000	20	10,000	ns	
t_{RCD}	\overline{RAS} to \overline{CAS} Delay Time	20	50	20	60	ns	14
t_{RAD}	\overline{RAS} to Column Address Delay Time	15	35	15	40	ns	15
t_{CRP}	\overline{CAS} to \overline{RAS} Precharge Time	5	-	5	-	ns	
t_{CP}	\overline{CAS} Precharge Time	10	-	10	-	ns	
t_{ASR}	Row Address Set-Up Time	0	-	0	-	ns	
t_{RAH}	Row Address Hold Time	10	-	10	-	ns	
t_{ASC}	Column Address Set-Up Time	0	-	0	-	ns	
t_{CAH}	Column Address Hold Time	10	-	15	-	ns	
t_{RAL}	Column Address To \overline{RAS} Lead Time	35	-	40	-	ns	
t_{RCS}	Read Command Set-Up Time	0	-	0	-	ns	
t_{RCH}	Read Command Hold Time	0	-	0	-	ns	11
t_{RRH}	Read Command Hold Time referenced to \overline{RAS}	0	-	0	-	ns	11
t_{WCH}	Write Command Hold Time	15	-	15	-	ns	

TC514260BJ/BFT-70/80

ELECTRICAL CHARACTERISTICS AND RECOMMENDED A.C. OPERATING CONDITIONS (CONT)

SYMBOL	PARAMETER	TC514260BJ/BFT				UNIT	NOTES
		-70		-80			
		MIN	MAX	MIN	MAX		
t_{WP}	Write Command Pulse Width	15	-	15	-	ns	
t_{RWL}	Write Command to RAS Lead Time	20	-	20	-	ns	
t_{CWL}	Write Command to CAS Lead Time	20	-	20	-	ns	
t_{DS}	Data Set-Up Time	0	-	0	-	ns	12
t_{DH}	Data Hold Time	15	-	15	-	ns	12
t_{REF}	Refresh Period	-	8	-	8	ns	
t_{WCS}	Write Command Set-Up Time	0	-	0	-	ns	13
t_{CWD}	CAS to WRITE Delay Time	50	-	50	-	ns	13
t_{RWD}	RAS to WRITE Delay Time	100	-	110	-	ns	13
t_{AWD}	Column Address to WE Delay Time	65	-	70	-	ns	13
t_{CPWD}	CAS Precharge to WRITE Delay Time	70	-	75	-	ns	13
t_{CSR}	CAS Set-Up Time (CAS before RAS Cycle)	5	-	5	-	ns	
t_{CHR}	CAS Hold Time (CAS before RAS Cycle)	15	-	15	-	ns	
t_{RPC}	RAS to CAS Precharge Time	5	-	5	-	ns	
t_{CPT}	CAS Precharge Time (CAS before RAS Counter Test Cycle)	30	-	30	-	ns	
t_{ROH}	RAS Hold Time referenced to OE	10	-	10	-	ns	
t_{OEA}	OE Access Time	-	20	0	20	ns	9
t_{OED}	OE to Data Delay	20	-	20	-	ns	
$t_{O EZ}$	Output buffer turn off Delay Time from OE	0	20	0	20	ns	10
t_{OEH}	OE Command Hold Time	20	-	20	-	ns	
t_{ODS}	Output Disable Set-Up Time	0	-	0	-	ns	

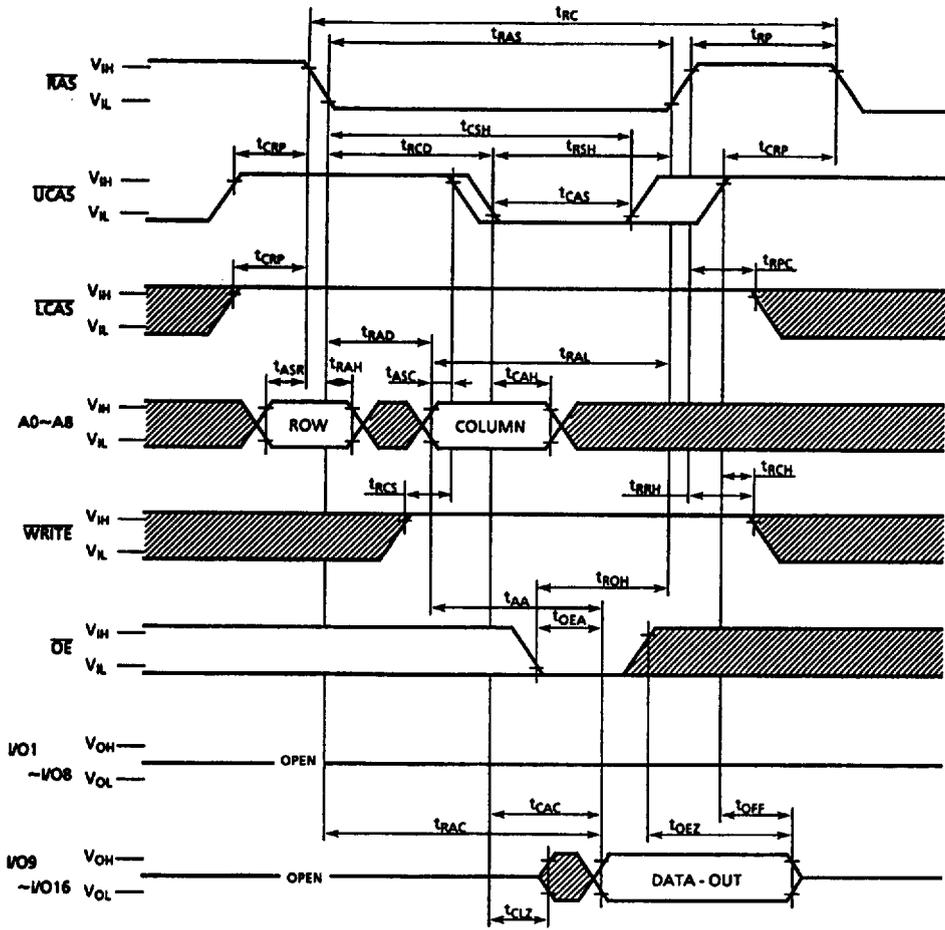
CAPACITANCE ($V_{CC} = 5V \pm 10\%$, $f = 1MHz$, $T_a = 0\sim 70^\circ C$)

SYMBOL	PARAMETER	MIN	MAX	UNIT
C_{I1}	Input Capacitance (A0~A8)	-	5	pF
C_{I2}	Input Capacitance (RAS, UCAS, LCAS, OE))	-	7	pF
C_O	Input Capacitance(I/O1~I/O16)	-	7	pF

NOTES:

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.
2. All voltages are referenced to V_{SS} .
3. I_{CC1} , I_{CC3} , I_{CC4} , I_{CC6} depend on cycle rate.
4. I_{CC1} , I_{CC4} depend on output loading. Specified values are obtained with the output open.
5. Address can be changed one or less while $\overline{RAS}=V_{IL}$. In case of I_{CC4} , it can be changed once or less during a fast page mode cycle (t_{PC}).
6. An initial pause of 200 μ s is required after power-up followed by 8 \overline{RAS} only refresh cycles before proper device operation is achieved. In case of using internal refresh counter, a minimum of 8 \overline{CAS} before \overline{RAS} refresh cycles instead of 8 \overline{RAS} only refresh cycles are required.
7. AC measurements assume $t_T=5$ ns.
8. V_{IH} (min.) and V_{IL} (max.) are reference levels for measuring timing of input signals. Also, transition times are measured between V_{IH} and V_{IL} .
9. Measured with a load equivalent to 2 TTL loads and 100pF.
10. t_{OFF} (max.) and t_{OEZ} (max.) define the time at which the output achieves the open circuit condition and are not referenced to output voltage levels.
11. Either t_{RCH} or t_{RRH} must be satisfied for a read cycle.
12. These parameters are referenced to \overline{UCAS} , \overline{LCAS} leading edge in early write cycles and to \overline{WRITE} , leading edge in Read-Modify-Write cycles.
13. t_{WCS} , t_{RWD} , t_{CWD} , t_{AWD} and t_{CPWD} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If $t_{WCS} \geq t_{WCS}$ (min.), the cycle is an early write cycle and the data output will remain open circuit (high impedance) through the entire cycle; If $t_{RWD} \geq t_{RWD}$ (min.), $t_{CWD} \geq t_{CWD}$ (min.), $t_{AWD} \geq t_{AWD}$ (min.) and $t_{CPWD} \geq t_{CPWD}$ (min.), (Fast Page Mode), the cycle is a Read-Modify-Write cycle and the data out will contain data read from the selected cell; If neither of the above sets of condition is satisfied, the condition of the data out (at access time) is indeterminate.
14. Operation within the t_{RCD} (max.) limit insures that t_{RAC} can be met. t_{RCD} (max.) is specified as a reference point only: If t_{RCD} is greater than the specified t_{RCD} (max.) limit, then access time is controlled by t_{CAC} .
15. Operation within the t_{RAD} (max.) limit insures that t_{RAC} (max.) can be met. t_{RAD} (max.) is specified as a reference point only: If t_{RAD} is greater than the specified t_{RAD} (max.) limit, then access time is controlled by t_{AA} .

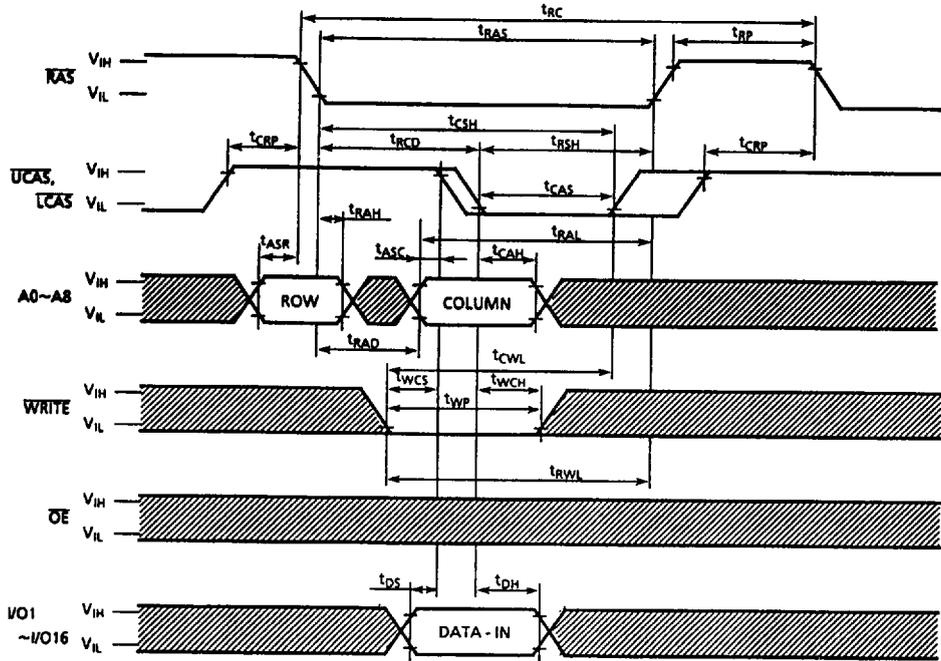
UPPER BYTE READ CYCLE



Note: $D_{IN}(I/O1 \sim I/O8) = \text{Don't Care}$
 $D_{IN}(I/O9 \sim I/O16) = \text{OPEN}$

▨ : "H" or "L"

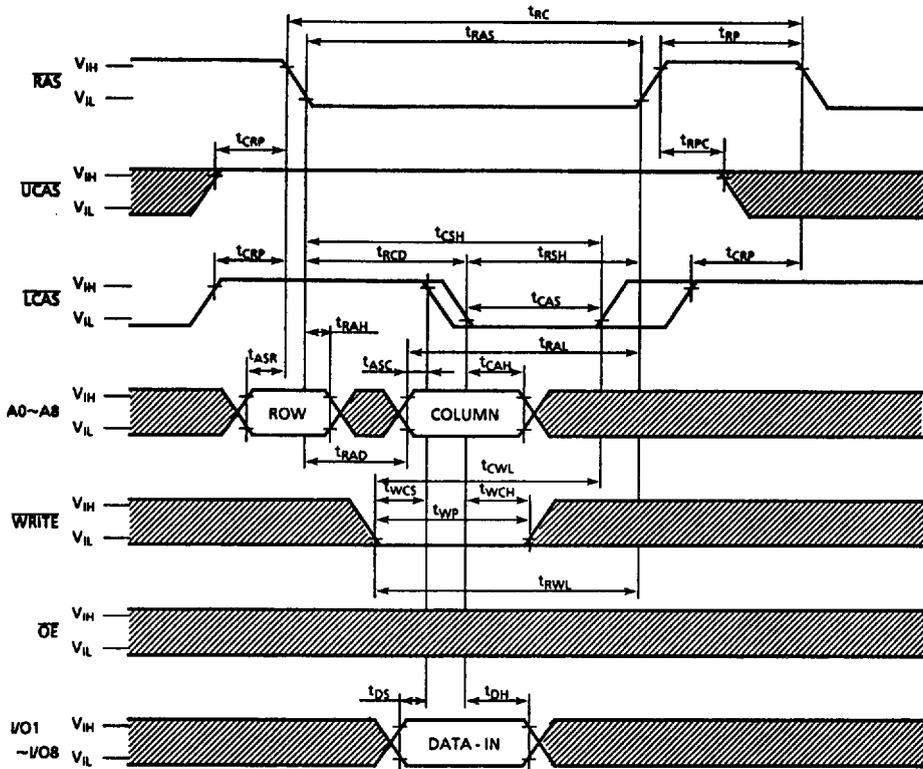
WRITE CYCLE (EARLY WRITE)



▨ : "H" or "L"

Note: $D_{OUT} = OPEN$

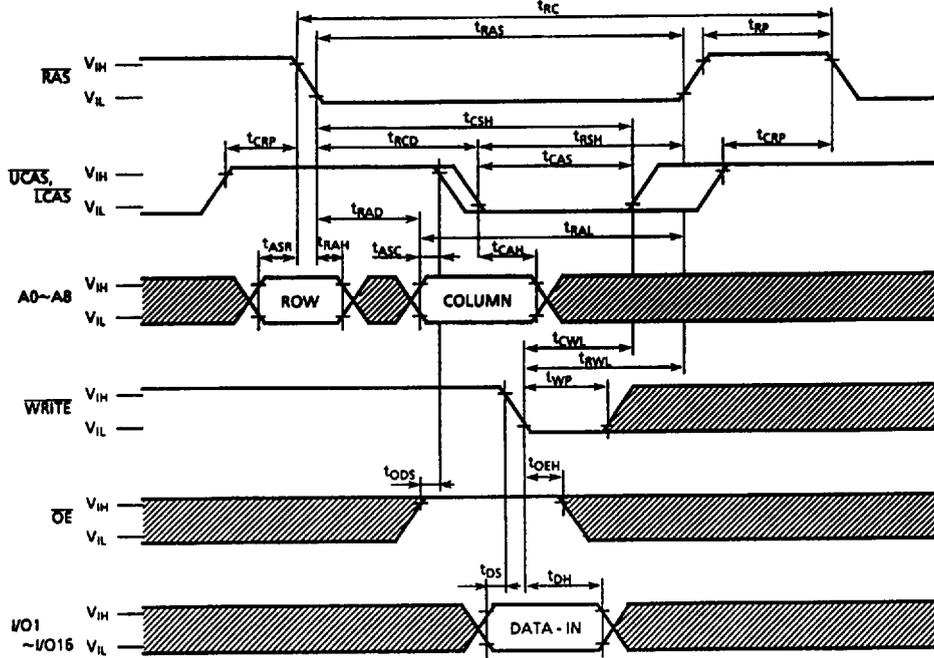
LOWER BYTE WRITE CYCLE (EARLY WRITE)



▨ : "H" or "L"

Note: D_{IN} (I/O9~I/O16) = Don't Care
 D_{OUT} = OPEN

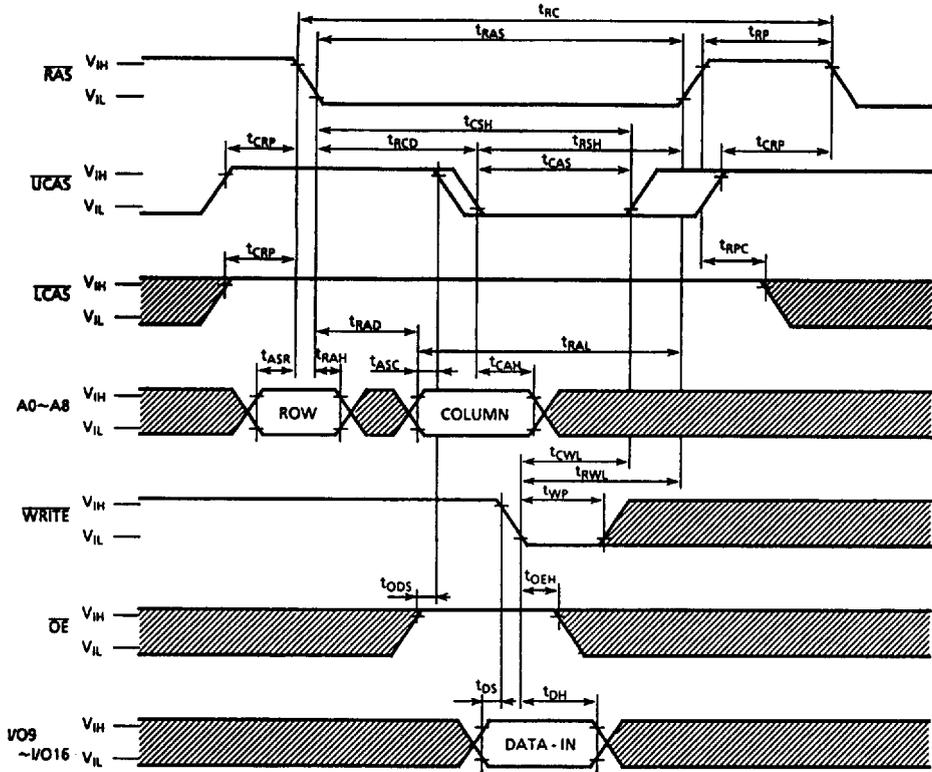
WRITE CYCLE (OE CONTROLLED WRITE)



Note: DOUT = OPEN

▨ : "H" or "L"

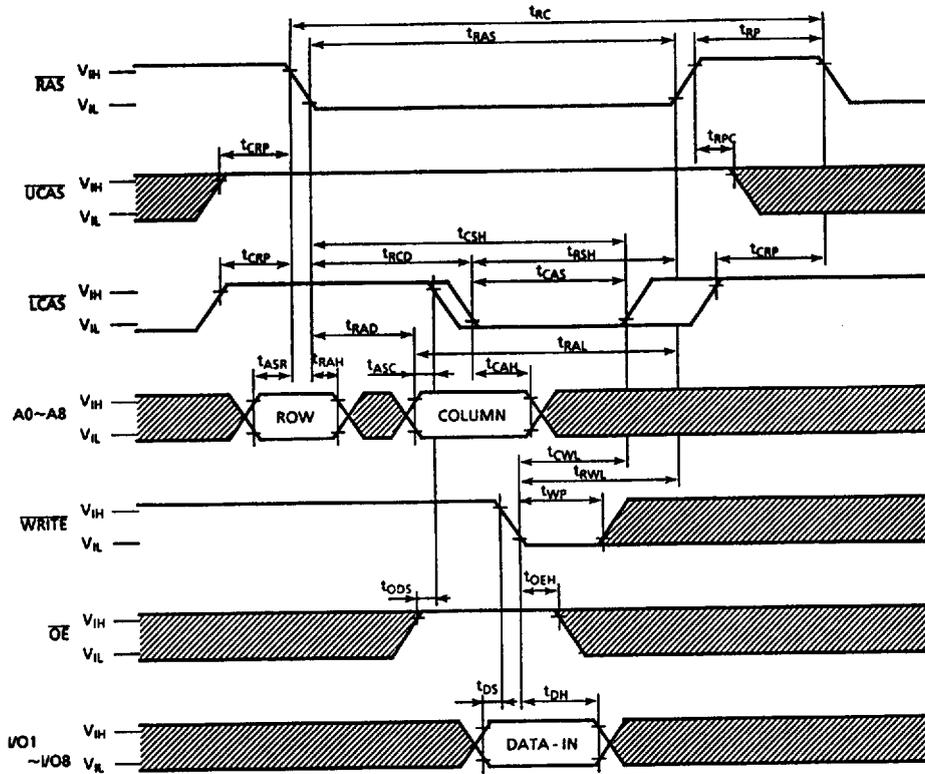
UPPER BYTE WRITE CYCLE (\overline{OE} CONTROLLED WRITE)



Note: D_{IN} (I/O1-I/O8) = Don't Care
 D_{OUT} = OPEN

■: "H" or "L"

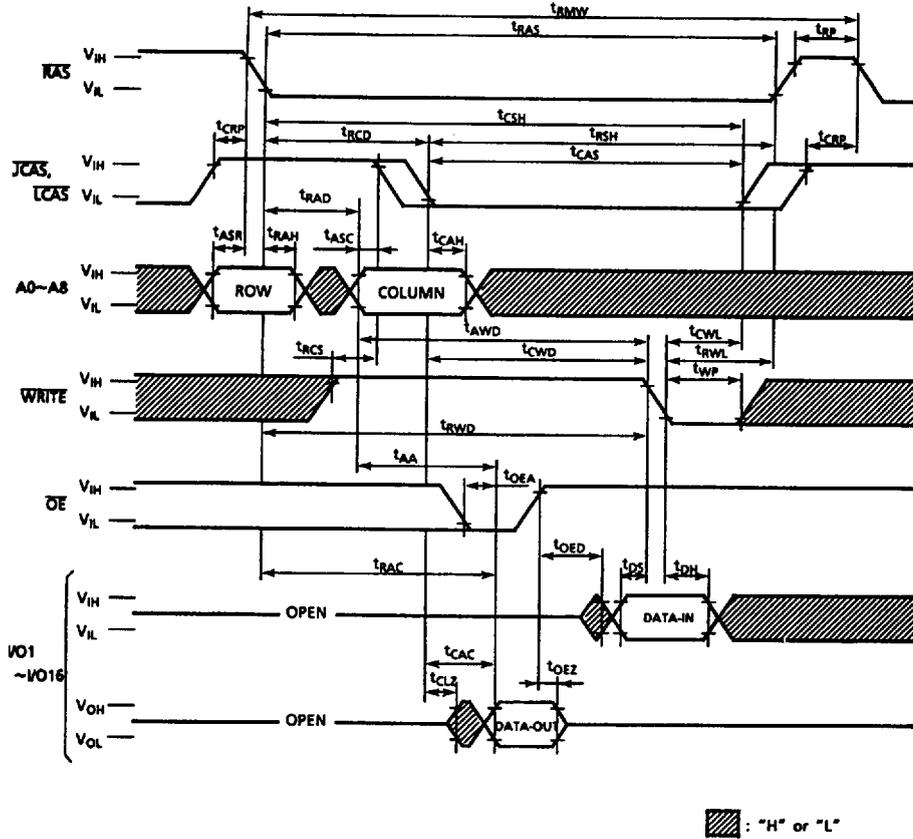
LOWER BYTE WRITE CYCLE (OE CONTROLLED WRITE)



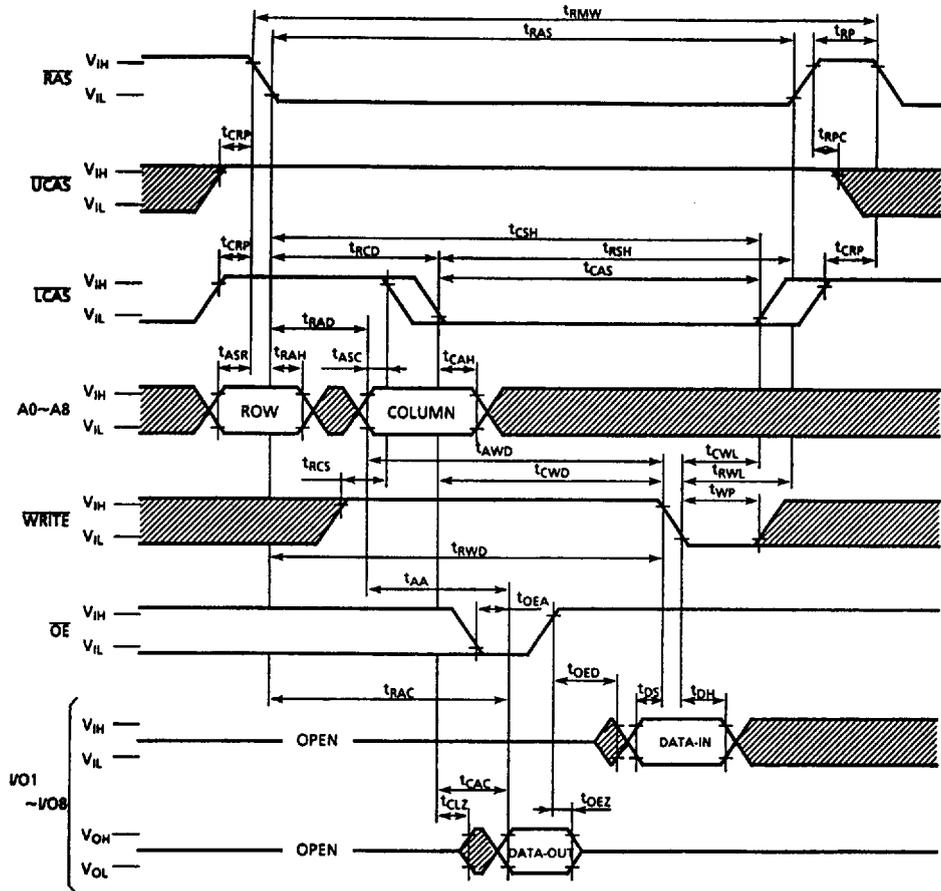
Note: D_{IN} (I/O9~I/O16) = Don't Care
 D_{OUT} = OPEN

■ : "H" or "L"

READ-MODIFY-WRITE CYCLE



LOWER BYTE READ-MODIFY-WRITE CYCLE

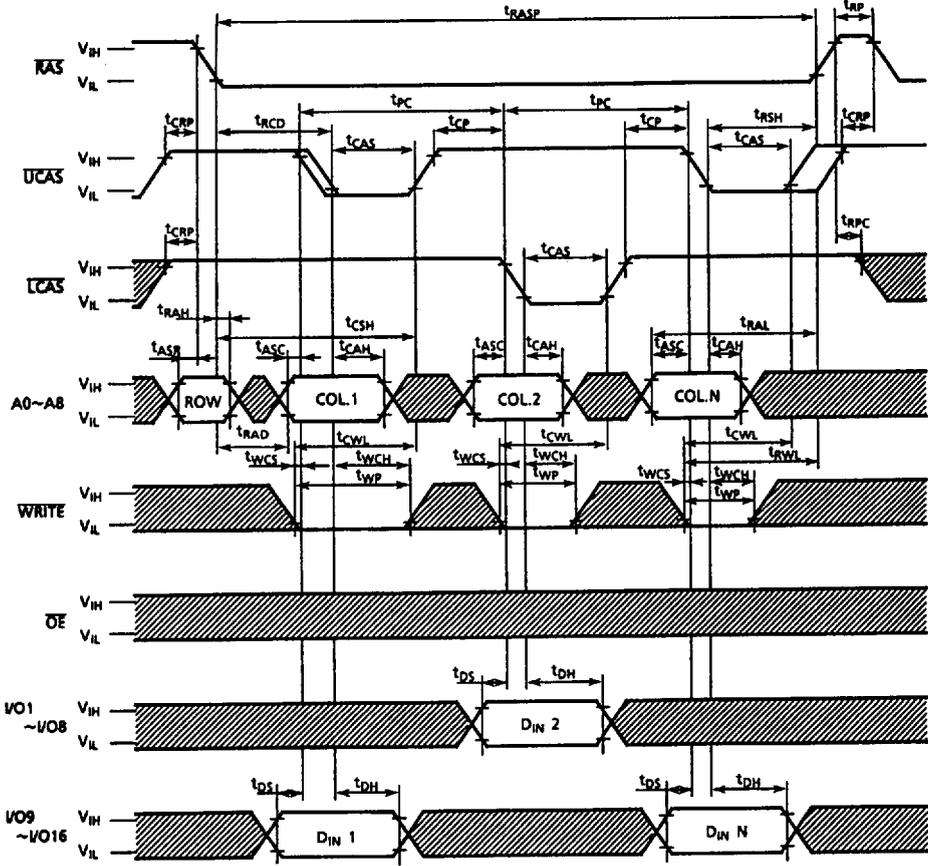


▨ : "H" or "L"

Note: $D_{IN}(I/O9 \sim I/O16)$ = Don't Care
 $D_{out}(I/O9 \sim I/O16)$ = OPEN

TC514260BJ/BFT-70/80

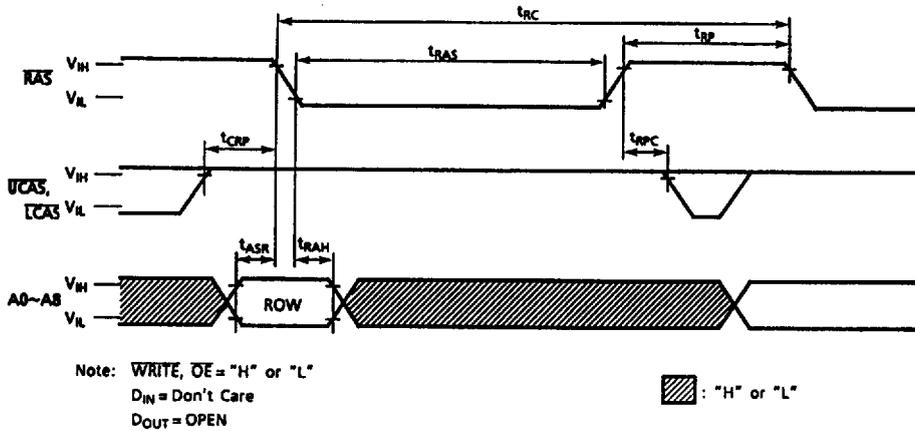
FAST PAGE MODE BYTE WRITE CYCLE (EARLY WRITE)



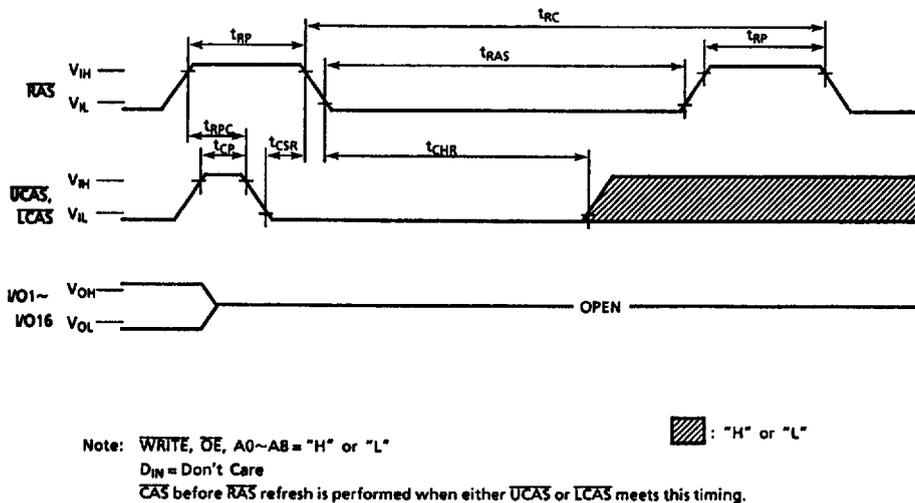
Note: DOUT = OPEN

▨ : "H" or "L"

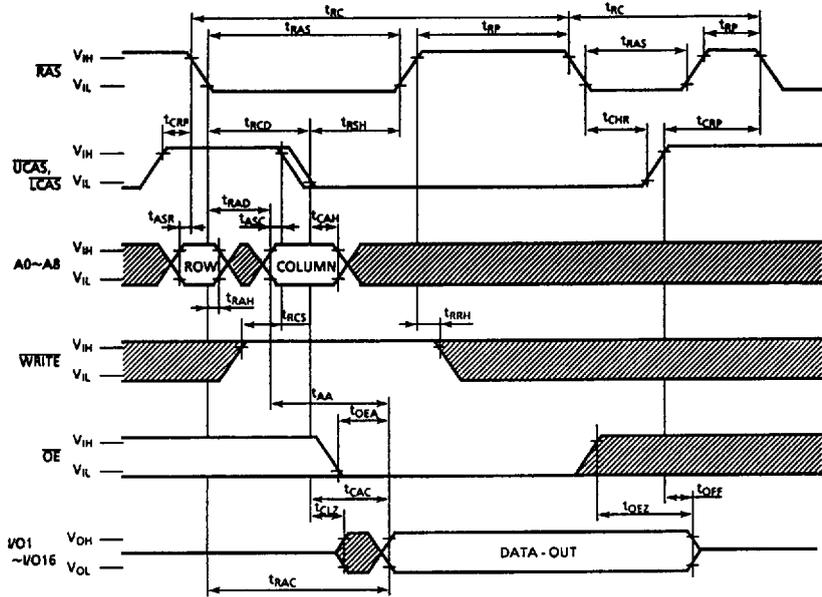
RAS ONLY REFRESH CYCLE



CAS BEFORE RAS REFRESH CYCLE



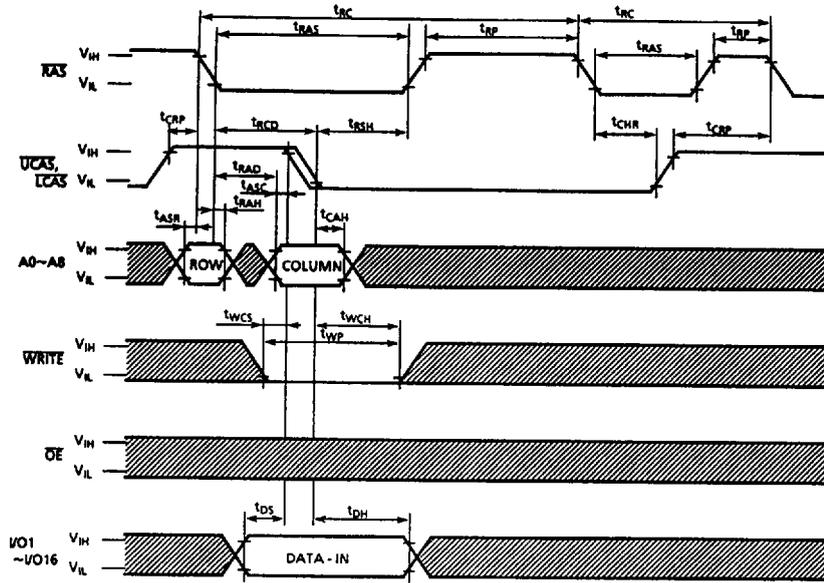
HIDDEN REFRESH CYCLE (READ)



Note: D_{IN} = OPEN

▨ : "H" or "L"

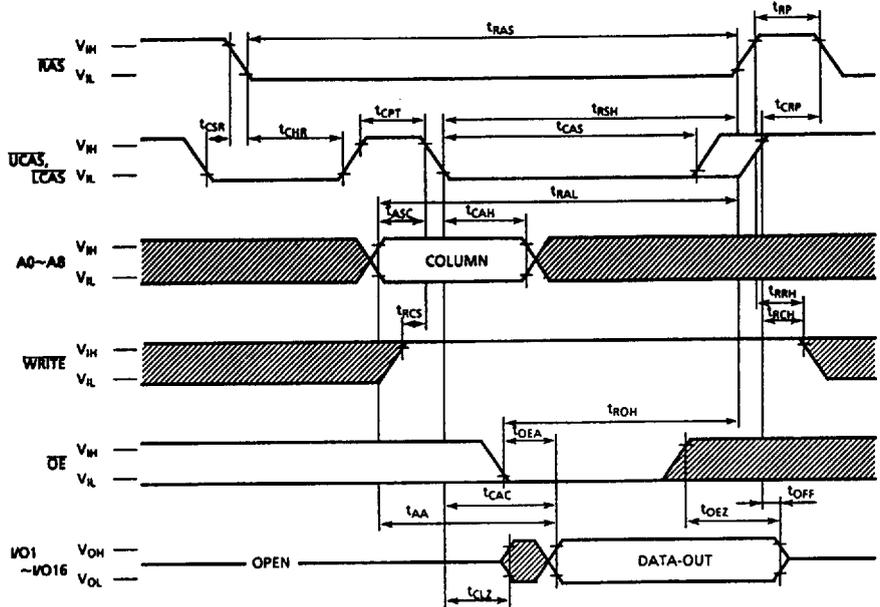
HIDDEN REFRESH CYCLE (WRITE)



Note: DOUT = OPEN

▨ : "H" or "L"

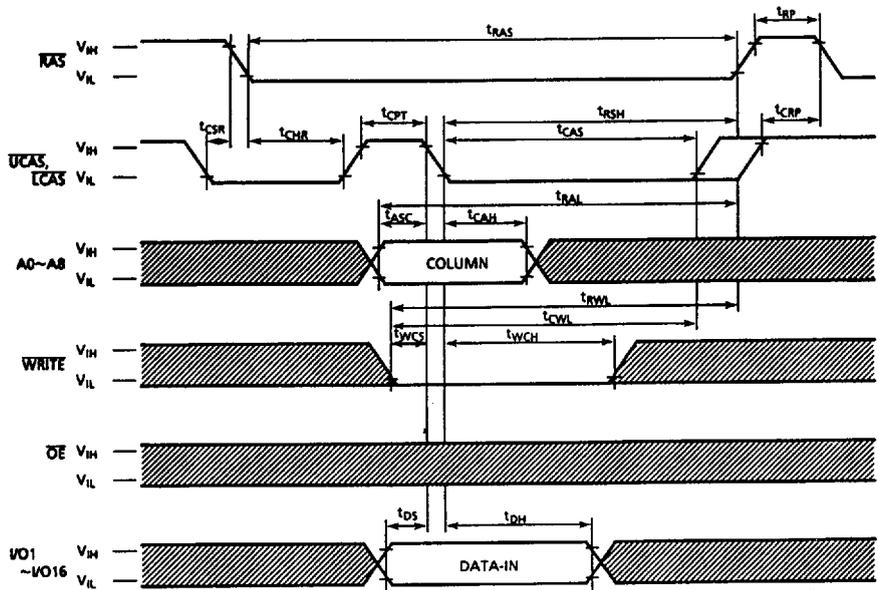
CAS BEFORE RAS REFRESH COUNTER TEST READ CYCLE



Note: $D_{IN} = OPEN$

▨: "H" or "L"

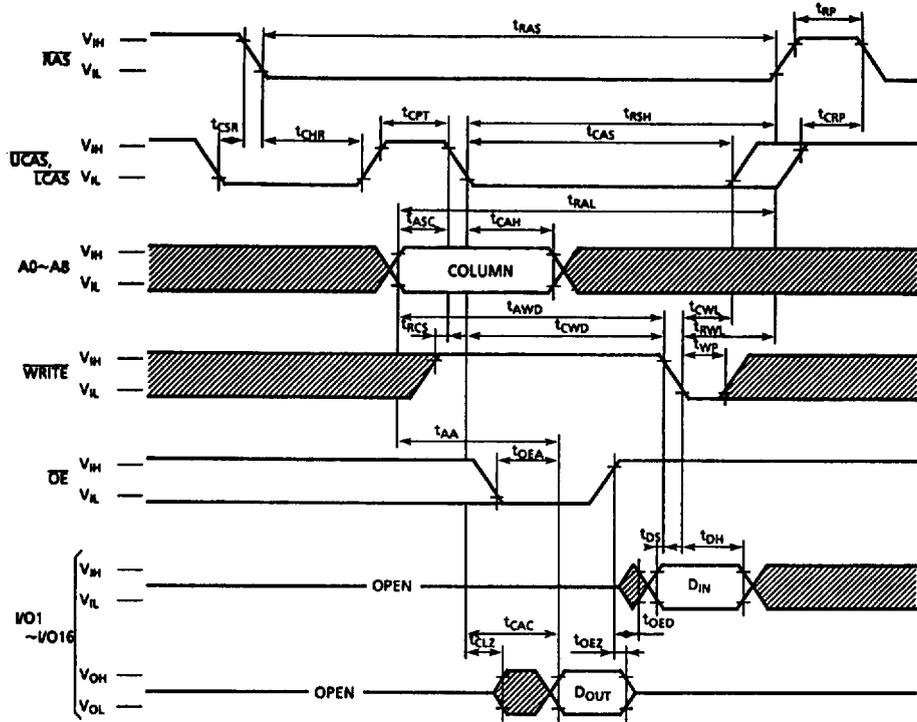
CAS BEFORE RAS REFRESH COUNTER TEST WRITE CYCLE



Note: $D_{OUT} = OPEN$

▨: "H" or "L"

CAS BEFORE RAS REFRESH COUNTER TEST READ-MODIFY-WRITE CYCLE



▨ : "H" or "L"